

# SE100PWTLG, SE100PWTLJ

Vishay General Semiconductor

AUTOMOTIVE

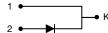
RoHS

COMPLIANT

HALOGEN FREE

# Surface-Mount Low V<sub>F</sub> Standard Rectifier





#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	10 A			
V <sub>RRM</sub>	400 V, 600 V			
I <sub>FSM</sub>	150 A			
$V_F$ at $I_F = 10 A (T_J = 125 °C)$	0.78			
T <sub>J</sub> max.	175 °C			
Package	SlimDPAK 2L			
Circuit configurations	Single			

#### **FEATURES**

- Creepage and clearance distance 2.8 mm minimum
- Very low profile typical height of 1.3 mm
- Ideal for automated placement
- · Oxide planar chip junction
- Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

General purpose, power line polarity protection, in both industry and automotive on board charger applications.

#### **MECHANICAL DATA**

Case: SlimDPAK 2L

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SE100PWTLG	SE100PWTLJ	UNIT	
Device marking code		SE100PWTLG	SE100PWTLJ		
Maximum repetitive peak reverse voltage	$V_{RRM}$	400	600	V	
Maximum average forward rectified current (Fig. 1)	I <sub>F(AV)</sub> (1)	10		۸	
	I <sub>F(AV)</sub> (2)	2.9		- A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	150		А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175		°C	

#### Notes

- (1) With infinite heatsink
- (2) Free air, mounted on recommended copper pad area

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Maximum Instantaneous forward voltage	$I_F = 5.0 \text{ A}$	$I_F = 5.0 \text{ A}$ $I_F = 10.0 \text{ A}$ $T_J = 25 \text{ °C}$	V <sub>E</sub> (1)	0.84	-	V
	$I_F = 10.0 A$			0.91	0.96	
	$I_F = 5.0 A$	- T <sub>J</sub> = 125 °C	'	0.7	-	
	$I_F = 10.0 A$		125 0	0.78	0.86	
Reverse current	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	5	μΑ
	nated V <sub>R</sub>	T <sub>J</sub> = 125 °C		12	70	
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	300	-	ns
Typical junction capacitance	4.0 V, 1 MHz		CJ	96	-	pF

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL TYP. MAX. UN			
Typical thormal registance	R <sub>0</sub> JA (1)(2)	75	94	°C/W
Typical thermal resistance	R <sub>0JM</sub> (3)	1.1	2	C/VV

#### Notes

- $^{(1)}$  The heat generated must be less than thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$
- (2) Thermal resistance junction to ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint
- (3) Thermal resistance junction-to-mount to follow JEDEC® 51-14 transient dual interface test method (TDIM)

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g) PREFERRED PACKAGE CO		BASE QUANTITY	DELIVERY MODE		
SE100PWTLJ-M3/I	0.185	I	4500	13" diameter plastic tape and reel		
SE100PWTLJHM3/I (1)	0.185	I	4500	13" diameter plastic tape and reel		

#### Note

(1) AEC-Q101 qualified



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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

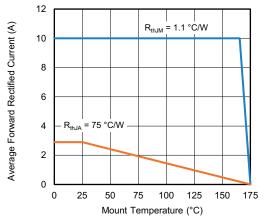
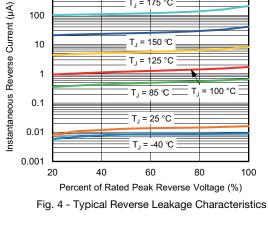


Fig. 1 - Maximum Forward Current Derating Curve



1000

T<sub>J</sub> = 175 °C

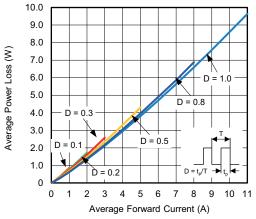


Fig. 2 - Forward Power Loss Characteristics

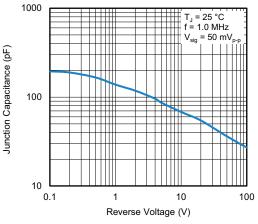


Fig. 5 - Typical Junction Capacitance

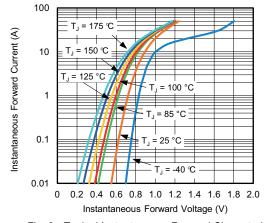


Fig. 3 - Typical Instantaneous Forward Characteristics

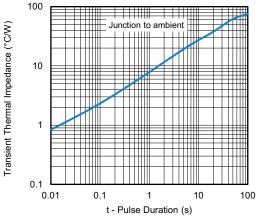
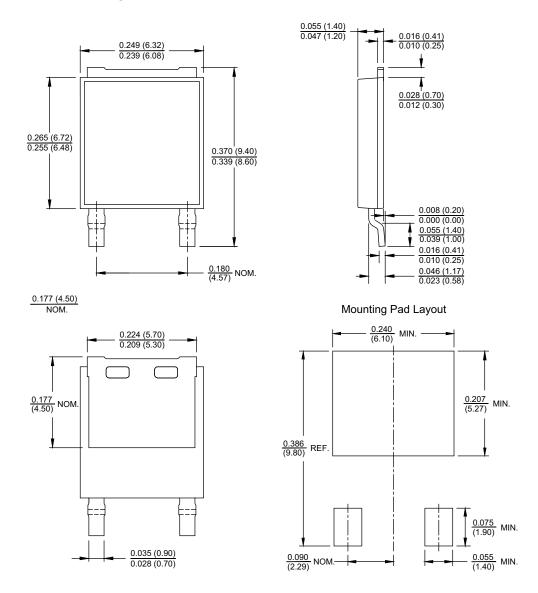


Fig. 6 - Typical Transient Thermal Impedance

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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### SlimDPAK 2L



#### Note

• The suggested mounting pad layout is provided for reference only, as actual pad layouts may vary depending on application



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